

MOSFETs Silicon N-channel MOS (U-MOSIV)

# SSM3K347R

## 1. Applications

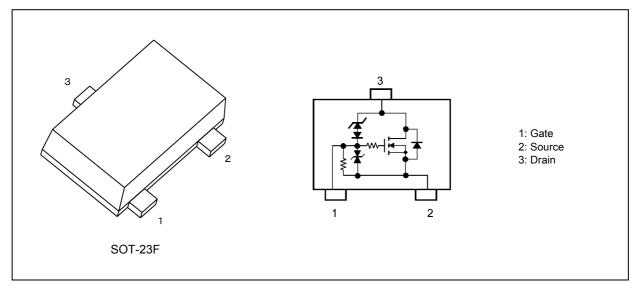
· Relay Drivers

#### 2. Features

- (1) AEC-Q101 (Rev. D) qualified. (Note 1)
- (2) 4.0 V drive
- (3) Built-in pull down resistance  $47 \text{ k}\Omega$ .
- (4) Low drain-source on-resistance
  - :  $R_{DS(ON)}$  = 480 m $\Omega$  (max) (@ $V_{GS}$  = 4.0 V)
  - $R_{DS(ON)} = 410 \text{ m}\Omega \text{ (max) (@V_{GS} = 4.5 V)}$
  - $R_{\mathrm{DS(ON)}} = 340~\mathrm{m}\Omega~\mathrm{(max)}~\mathrm{(@V_{GS}} = 10~\mathrm{V)}$

Note 1: For detail information, please contact to our sales.

## 3. Packaging and Pin Assignment





## 4. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V <sub>DS(DC)</sub>	38	V
Gate-source voltage			$V_{GSS}$	±20	
Drain current (DC)		(Note 1)	I <sub>D</sub>	2	Α
Drain current (pulsed)		(Note 1), (Note 2)	I <sub>DP</sub>	4	
Power dissipation		(Note 3)	$P_D$	1	W
Power dissipation	(t = 10 s)	(Note 3)	$P_{D}$	2	
Channel temperature			T <sub>ch</sub>	150	°C
Single-pulse active clamp capability		(Note 4)	E <sub>AS</sub>	2.2	mJ
Storage temperature			T <sub>stg</sub>	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Ensure that the channel temperature does not exceed 150 °C.
- Note 2: pulse width  $\leq$  10  $\mu$ s, Duty  $\leq$  1 %
- Note 3: Device mounted on a 25.4 mm × 25.4 mm × 1.6 mm FR4 glass epoxy board (Cu pad: 645 mm<sup>2</sup>)
- Note 4:  $V_{DD}$  = 25 V,  $T_{ch}$  = 25 °C (Initial state)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, R<sub>th(ch-a)</sub>, and the drain power dissipation, P<sub>D</sub>, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.



#### 5. Electrical Characteristics

## 5.1. Static Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Drain-source clamp voltage		V <sub>(CL)DSS</sub>	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	38	43	48	V
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 24 V, V <sub>GS</sub> = 0 V	_		10	μА
Gate leakage current		I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$	_	_	±152	
Gate threshold voltage	(Note 1)	$V_{th}$	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.4	_	2.4	V
Forward transfer admittance	(Note 2)	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 A	_	4.1	_	S
Drain-source on-resistance	(Note 2)	R <sub>DS(ON)</sub>	I <sub>D</sub> = 0.5 A, V <sub>GS</sub> = 4.0 V	_	350	480	mΩ
			I <sub>D</sub> = 1.0 A, V <sub>GS</sub> = 4.5 V	_	340	410	
			I <sub>D</sub> = 1.0 A, V <sub>GS</sub> = 10 V	_	280	340	
Pull-down resistance		R <sub>pd</sub>	_	32.9	47	61.1	kΩ

Note 1: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (0.1 mA for this device). Then, for normal switching operation,  $V_{GS(ON)}$  must be higher than  $V_{th}$ , and  $V_{GS(OFF)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .

Take this into consideration when using the device.

Note 2: Pulse measurement.

## 5.2. Dynamic Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$	_	86	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1 MHz	_	13		
Output capacitance	Coss		_	27	_	
Switching time (turn-on time)	t <sub>on</sub>	$V_{DD} = 20 \text{ V}, I_D = 0.5 \text{ A},$ $V_{GS} = 0 \text{ to } 4.5 \text{ V}, R_G = 50 \Omega$	_	380	_	ns
Switching time (turn-off time)	t <sub>off</sub>	Duty $\leq$ 1 %, Input: $t_r$ , $t_f$ < 5 ns, Common source, See Chapter 5.3.	_	800	_	

#### 5.3. Switching Time Test Circuit

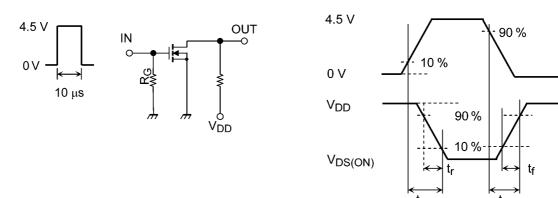


Fig. 5.3.1 Switching Time Test Circuit

Fig. 5.3.2 Input Waveform/Output Waveform

## 5.4. Gate Charge Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} = 20 \text{ V}, I_D = 1.0 \text{ A},$	_	2.5	_	nC
Gate-source charge 1	Q <sub>gs1</sub>	V <sub>GS</sub> = 10 V	_	0.8	_	
Gate-drain charge	Q <sub>gd</sub>		_	0.5	_	



# 5.5. Source-Drain Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage (Note 1)	V <sub>DSF</sub>	I <sub>D</sub> = -2 A, V <sub>GS</sub> = 0 V	_	-0.87	-1.2	V

Note 1: Pulse measurement.

## 6. Marking

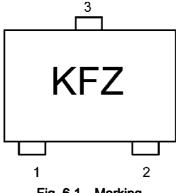


Fig. 6.1 Marking

## 7. Characteristics Curves (Note)

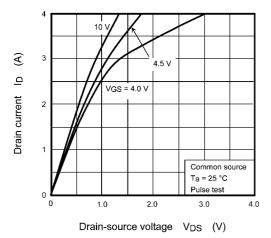


Fig. 7.1 I<sub>D</sub> - V<sub>DS</sub>

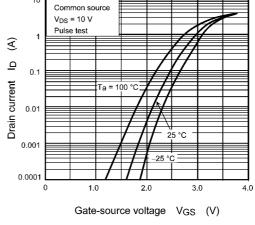


Fig. 7.2 I<sub>D</sub> - V<sub>GS</sub>

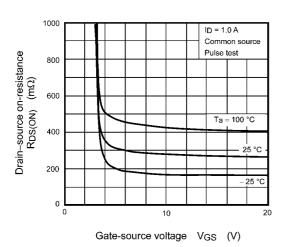


Fig. 7.3  $R_{DS(ON)} - V_{GS}$ 

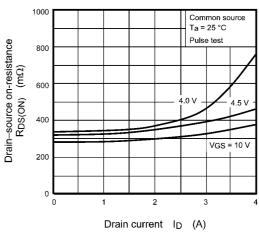


Fig. 7.4 R<sub>DS(ON)</sub> - I<sub>D</sub>

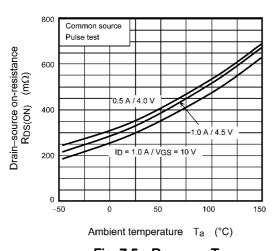


Fig. 7.5 R<sub>DS(ON)</sub> - T<sub>a</sub>

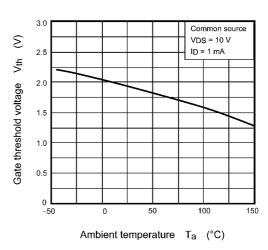


Fig. 7.6 V<sub>th</sub> - T<sub>a</sub>

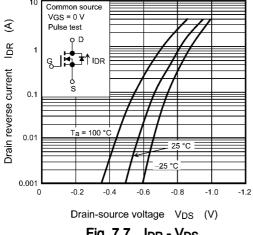


Fig. 7.7 IDR - VDS

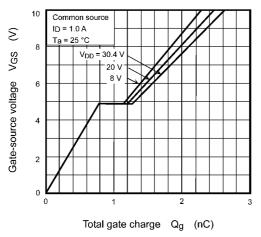


Fig. 7.9 Dynamic Input Characteristics

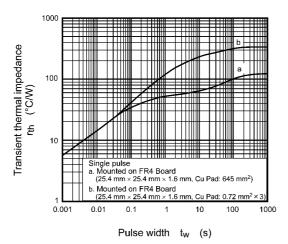


Fig. 7.11 rth - tw

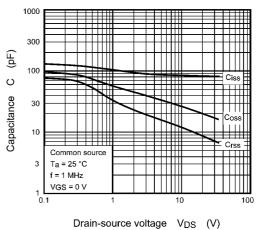


Fig. 7.8 C - V<sub>DS</sub>

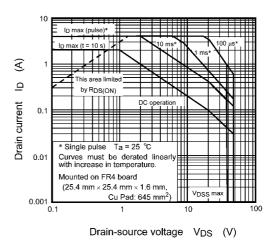


Fig. 7.10 Safe Operating Area

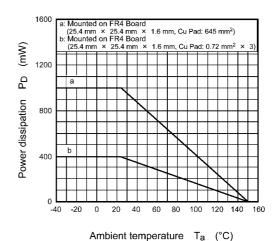
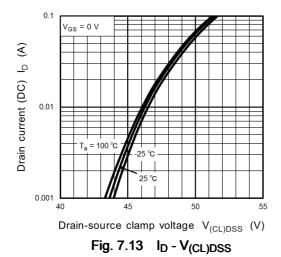
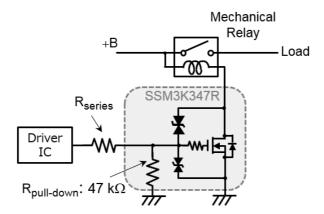


Fig. 7.12 P<sub>D</sub> - T<sub>a</sub>



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## 8. ACTIVE CLAMP APPLICATION

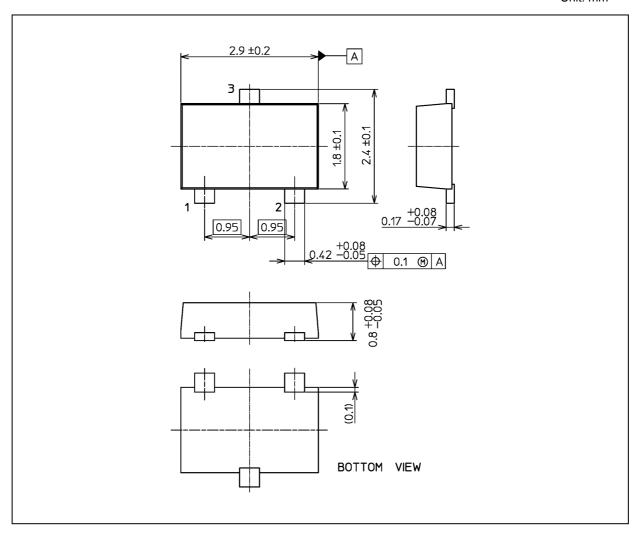


 $\text{R}_{\text{series}}\text{:}$  Input series resistance is necessary to set to a value (range: 1 k $\Omega$  to 5 k $\Omega)$ 



# **Package Dimensions**

Unit: mm



Weight: 0.011 g (typ.)

	Package Name(s)
Nickname: SOT-23F	



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